

WHAT IS CLAIMED IS:

1           1.       A semiconductor device formed by combining and placing previously registered  
2       functional blocks, and determining a wiring pattern in accordance with given logical circuit  
3       specifications, said semiconductor device comprising:

4               a first functional block including at least one of:

5                       a first conduction type diode having a first conduction type diffusion layer connected  
6       to an input pin of the first functional block and a second conduction type well connected to a  
7       second power supply, and,

8                       a second conduction type diode having a second conduction type diffusion layer  
9       connected to the input pin and a first conduction type well connected to a first power supply; and

10               a second functional block including the same logic and the same drive capability as the first  
11       functional block but not containing said first or second conduction type diode,

12               wherein either the first functional block or the second functional block is selectively used  
13       depending on whether or not a wiring conductor conducting to the input pin and a gate electrode  
14       becomes an antenna ratio exceeding an allowed antenna ratio in said semiconductor device when  
15       the antenna ratio is a ratio between an area of the wiring conductor conducting to the gate electrode  
16       and an area of the gate electrode.

1           2.     A semiconductor device design method for forming a semiconductor device by  
2     combining and placing previously registered functional blocks, and determining a wiring pattern in  
3     accordance with given logical circuit specifications, said design method comprising:

4           a registration step of previously registering a first functional block having a first conduction  
5     type diode comprising a first conduction type diffusion layer connected to an input pin of the  
6     functional block, and a second conduction type well connected to a second power supply or a  
7     second conduction type diode comprising a second conduction type diffusion layer connected to the  
8     input pin and a first conduction type well connected to a first power supply and a second functional  
9     block having the same logic as and the same drive capability as the first functional block but not  
10    containing the first or second conduction type diode;

11          a determination step of determining whether or not a wiring conductor conducting to the  
12    input pin and a gate electrode becomes an antenna ratio exceeding an allowed antenna ratio in said  
13    semiconductor device when the antenna ratio is a ratio between an area of the wiring conductor  
14    conducting to the gate electrode and an area of the gate electrode; and

15          a selection step of selectively using the first functional block, if said determination step  
16    determines that the input pin conducts to the gate electrode exceeding the antenna ratio.

1           3.     A computer-readable recording medium storing the semiconductor device design  
2     method as claimed in claim 2 as a program for causing a computer to execute the semiconductor  
3     device design method.

1           4.     A semiconductor device design support system for automatically forming a  
2     semiconductor device by combining and placing previously registered functional blocks, and  
3     determining a wiring pattern in accordance with given logical circuit specifications, said design  
4     support system comprising:

5                 registration means for previously registering a first functional block having a first conduction  
6     type diode comprising a first conduction type diffusion layer connected to an input pin of the  
7     functional block and a second conduction type well connected to a second power supply or a  
8     second conduction type diode comprising a second conduction type diffusion layer connected to the  
9     input pin and a first conduction type well connected to a first power supply and a second functional  
10    block having the same logic as and the same drive capability as the first functional block but not  
11    containing the first or second conduction type diode and;

12                determination means for determining whether or not a wiring conductor conducting to the  
13    input pin and a gate electrode becomes an antenna ratio exceeding an allowed antenna ratio in said  
14    semiconductor device when the antenna ratio is a ratio between an area of the working conductor  
15    conducting to the gate electrode and an area of the gate electrode; and

16                selection means for selectively using the first functional block, if said determination means  
determines that the input pin conducts to the gate electrode exceeding the antenna ratio.